DATASHEET

Description

The 9FGU0231 is a member of IDT's 1.5V Ultra-Low-Power PCIe clock family. The device has 2output enables for clock management, 2 different spread spectrum levels in addition to spread off and 2 selectable SMBus addresses.

Recommended Application

1.5V PCIe Gen1-2-3 clock generator

Output Features

- 2 100MHz Low-Power (LP) HCSL DIF pairs
- 1 1.5V LVCMOS REF output w/Wake-On-LAN (WOL) support

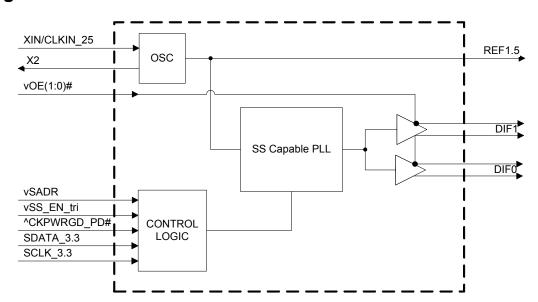
Key Specifications

- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew <50ps
- DIF phase jitter is PCIe Gen1-2-3 compliant
- REF phase jitter is < 3.0ps RMS

Features/Benefits

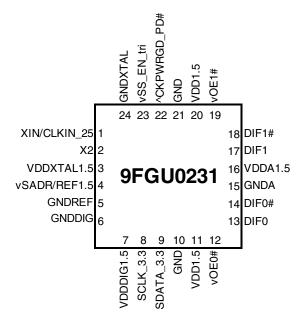
- LP-HCSL outputs; save 4 resistors compared to standard PCIe devices
- 23mW typical power consumption; reduced thermal concerns
- OE# pins; support DIF power management
- Programmable Slew rate for each output; allows tuning for various line lengths
- Programmable output amplitude; allows tuning for various application environments
- DIF outputs blocked until PLL is locked; clean system start-up
- Selectable 0%, -0.25% or -0.5% spread on DIF outputs; reduces EMI
- External 25MHz crystal; supports tight ppm with 0 ppm synthesis error
- Configuration can be accomplished with strapping pins; SMBus interface not required for device control
- Selectable SMBus addresses; multiple devices can easily share an SMBus segment
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 24-pin 4x4 mm VFQFPN; minimal board space

Block Diagram





Pin Configuration



24-pin VFQFPN, 4x4 mm, 0.5mm pitch

^ prefix indicates internal 120KOhm pull up resistor v prefix indicates internal 120KOhm pull down resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write Bit
State of SADR on first application	0	1101000	Х
of CKPWRGD_PD#	1	1101010	Х

Power Management Table

CKPWRGD_PD#	SMBus	MBus DIFx		
CKFWKGD_FD#	OE bit	True O/P	Comp. O/P	REF
0	Х	Low	Low	Hi-Z ¹
1	1	Running	Running	Running
1	0	Low	Low	Low

^{1.} REF is Hi-Z until the 1st assertion of CKPWRGD_PD# high. After this, when CKPWRG_PD# is low, REF is Low.

Power Connections

Pin Number		Decemention
VDD	GND	Description
3	5,24	XTAL, REF
7	6	Digital
11,20	10,21	DIF outputs
16	15	PLL Analog

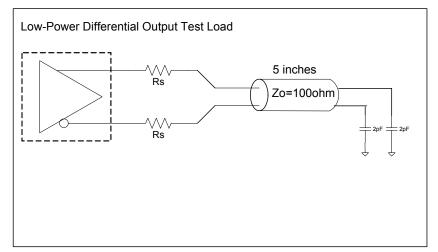


Pin Descriptions

	- I=	_	
Pin#	Pin Name	Type	Pin Description
1	XIN/CLKIN_25	IN	Crystal input or Reference Clock input. Nominally 25MHz.
2	X2	OUT	Crystal output.
3	VDDXTAL1.5	PWR	Power supply for XTAL, nominal 1.5V
4	vSADR/REF1.5	LATCHED I/O	Latch to select SMBus Address/1.5V LVCMOS copy of X1/REFIN pin
5	GNDREF	GND	Ground pin for the REF outputs.
6	GNDDIG	GND	Ground pin for digital circuitry
7	VDDDIG1.5	PWR	1.5V digital power (dirty power)
8	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
9	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
10	GND	GND	Ground pin.
11	VDD1.5	PWR	Power supply, nominally 1.5V
12	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
13	DIF0	OUT	Differential true clock output
14	DIF0#	OUT	Differential Complementary clock output
15	GNDA	GND	Ground pin for the PLL core.
16	VDDA1.5	PWR	1.5V power for the PLL core.
17	DIF1	OUT	Differential true clock output
18	DIF1#	OUT	Differential Complementary clock output
19	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
20	VDD1.5	PWR	Power supply, nominally 1.5V
21	GND	GND	Ground pin.
22	^CKPWRGD_PD#	IN	Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal pull-up resistor.
23	vSS_EN_tri	LATCHED IN	Latched select input to select spread spectrum amount at initial power up : 1 = -0.5% spread, M = -0.25%, 0 = Spread Off
24	GNDXTAL	GND	GND for XTAL

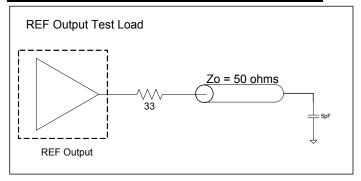


Test Loads

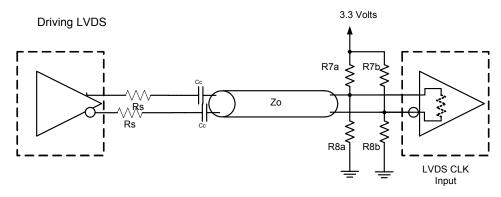


Alternate Differential Output Terminations

Rs	Zo	Units
33	100	Ohms
27	85	Offilis



Alternate Terminations



Driving LVDS inputs

Ditting 1120 inputs								
	,	Value						
	Receiver has	Receiver does not						
Component	termination	have termination	Note					
R7a, R7b	10K ohm	140 ohm						
R8a, R8b	5.6K ohm	75 ohm						
Cc	0.1 uF	0.1 uF						
Vcm	1.2 volts	1.2 volts						



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9FGU0231. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDxx	Applies to all VDD pins	-0.5		2	V	1,2
Input Voltage	V_{IN}		-0.5		$V_{DD}+0.5V$	V	1,3
Input High Voltage, SMBus	V _{IHSMB}	SMBus clock and data pins			3.3V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Current Consumption

TA = T_{AMR}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

A = TAMB; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions							
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	I _{DDAOP}	VDDA, All outputs active @100MHz		6.2	9	mA	
Operating Supply Current	I _{DDOP}	All VDD, except VDDA, All outputs active @100MHz		8.9	14	mA	
Wake-on-LAN Current (CKPWRGD_PD# = '0' Byte 3, bit 5 = '1')	I _{DDAPD}	VDDA, DIF outputs off, REF output running		0.4	1	mA	2
	I _{DDPD}	All VDD, except VDDA, DIF outputs off, REF output running		3.9	6	mA	2
Powerdown Current	I _{DDAPD}	VDDA, all outputs off		0.4	1	mA	
(CKPWRGD_PD# = '0' Byte 3, bit 5 = '0')	I _{DDPD}	All VDD, except VDDA and VDDIO, all outputs off		0.4	1	mA	

¹ Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-DIF Output Duty Cycle, Jitter, and Skew Characteristics

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

_	71112, 117		, , , , , , , , , , , , , , , , , , ,					
	PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50	55	%	1,2
	Skew, Output to Output	t _{sk3}	Averaging on, $V_T = 50\%$		32	50	ps	1
Γ	Jitter, Cycle to cycle	t _{jcyc-cyc}			16	50	ps	1,2

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.5V.

² This is the current required to have the REF output running in Wake-on-LAN mode (Byte 3, bit 5 = 1)

² Measured from differential waveform



Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDxx	Supply voltage for core, analog and single-ended LVCMOS outputs	1.425	1.5	1.575	٧	
Ambient Operating	-	Comercial range	0	25	70	°C	
Temperature	T_{AMB}	Industrial range	-40	25	85	°C	
Input High Voltage	V_{IH}	Single-ended inputs, except SMBus	0.75 V _{DD}		$V_{DD} + 0.3$	V	
Input Mid Voltage	V_{IM}	Single-ended tri-level inputs ('_tri' suffix)	0.4 V _{DD}	0.5 V _{DD}	0.6 V _{DD}	V	
Input Low Voltage	V_{IL}	Single-ended inputs, except SMBus	-0.3		0.25 V _{DD}	V	
Output High Voltage	V _{IH}	Single-ended outputs, except SMBus. I _{OH} = -2mA	V _{DD} -0.45			V	
Output Low Voltage	V_{IL}	Single-ended outputs, except SMBus. I _{OL} = -2mA			0.45	V	
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
Input Current		Single-ended inputs					
input Current	I _{INP}	$V_{IN} = 0 V$; Inputs with internal pull-up resistors	-200		200	uA	
		V_{IN} = VDD; Inputs with internal pull-down resistors					
Input Frequency	F_{in}	XTAL, or X1 input	23	25	27	MHz	
Pin Inductance	L_{pin}				7	nH	1
Capacitance	C_{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Сараспапсе	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	т	From V _{DD} Power-Up and after input clock		1.8	ms	1,2	
CIK Stabilization	T _{STAB}	stabilization or de-assertion of PD# to 1st clock			1.0	1115	1,2
SS Modulation Frequency	f_{MOD}	Triangular Modulation	30	31.6	33	kHz	1
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	1		3	clocks	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	V _{ILSMB}				0.6	V	
SMBus Input High Voltage	V _{IHSMB}	$V_{DDSMB} = 3.3V$, see note 4 for $V_{DDSMB} < 3.3V$	2.1		3.3	V	4
SMBus Output Low Voltage	V_{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	
Nominal Bus Voltage	V _{DDSMB}		1.425		3.3	V	
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Control input must be monotonic from 20% to 80% of input swing.

³ Time from deassertion until outputs are >200 mV

 $^{^4}$ For $V_{\text{DDSMB}} < 3.3 V, \ V_{\text{IHSMB}} >= 0.8 x V_{\text{DDSMB}}$



Electrical Characteristics-DIF Low-Power HCSL Outputs

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

AIVID, 117							
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on fast setting	1.1	2.2	3.3	V/ns	1,2,3
Siew rate	111	Scope averaging on slow setting	0.9	1.7	2.6	V/ns	1,2,3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		3	20	%	1,2,4
Voltage High	V_{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	600	735	850	mV	7
Voltage Low	V_{LOW}	averaging on)	-150	-16	150	1117	7
Max Voltage	Vmax	Measurement on single ended signal using		779	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-45		IIIV	7
Vswing	Vswing	Scope averaging off	300	1503		mV	1,2,7
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	405	550	mV	1,5,7
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		12	140	mV	1,6,7

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-DIF Output Phase Jitter Parameters

TA = T_{AMB}: Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	IND. LIMIT	UNITS	Notes
	t _{iphPCleG1}	PCIe Gen 1		27.7	40	86	ps (p-p)	1,2,3,5
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.0	1.3	3	ps (rms)	1,2,3,5
Phase Jitter, PLL Mode	^I jphPCleG2	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		1.9	2.2	3.1	ps (rms)	1,2,3,5
,	t _{jphPCleG3}	PCIe Gen 3 Common Clock Architecture (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz)		0.4	0.6	1	ps (rms)	1,2,3,5
	t _{jphPCleG3SRn} S	PCIe Gen 3 Separate Reference No Spread (SRnS) (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz)		0.4	0.6	0.7	ps (rms)	1,2,3,5

¹ Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus amplitude settings.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ Calculated from Intel-supplied Clock Jitter Tool

⁵ Applies to all differential outputs



Electrical Characteristics-REF

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Long Accuracy	ppm	see Tperiod min-max values		0		ppm	1,2
Clock period	T _{period}	25 MHz output		40		ns	2
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = 1F, 20% to 80% of VDDREF	0.3	0.7	1.1	V/ns	1
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = 5F, 20% to 80% of VDDREF	0.5	1.0	1.6	V/ns	1,3
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = 9F, 20% to 80% of VDDREF	0.77	1.3	1.9	V/ns	1
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = DF, 20% to 80% of VDDREF	0.84	1.4	2.0	V/ns	1
Duty Cycle	d _{t1X}	$V_T = VDD/2 V$	45	47.1	55	%	1,4
Duty Cycle Distortion	d _{tcd}	$V_T = VDD/2 V$, when driven by XIN/CLKIN_25 pin	0	2.0	4	%	1,5
Jitter, cycle to cycle	t _{jcyc-cyc}	$V_T = VDD/2 V$		51.2	250	ps	1,4
Noise floor	t _{jdBc1k}	1kHz offset		-126	-105	dBc	1,4
Noise floor	t _{jdBc10k}	10kHz offset to Nyquist		-139	-110	dBc	1,4
Jitter, phase	t _{jphREF}	12kHz to 5MHz		1.11	3	ps (rms)	1,4

¹Guaranteed by design and characterization, not 100% tested in production.

Clock Periods-Differential Outputs with Spread Spectrum Disabled

				Me	easurement W	'indow				
	Comton	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2

Clock Periods-Differential Outputs with -0.5% Spread Spectrum Enabled

		Measurement Window								
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC ON	Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2

¹Guaranteed by design and characterization, not 100% tested in production.

² All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

³ Default SMBus Value

⁴ When driven by a crystal.

⁵ X2 should be floating.

² All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz



General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Blo	ock \	Write Operation
Control	ler (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave	Address		
WR	WRite		
			ACK
Beginnin	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnii	ng Byte N		
			ACK
0		\perp	
0		X Byte	0
0		.e	0
			0
Byte N	l + X - 1		
			ACK
Р	stoP bit		·

Note: Read/Write address is determined by SADR latch.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read C	peration
Co	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	inning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		e)	0
	0	X Byte	0
	0		0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		



SMBus Table: Output Enable Register

Byte 0	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				1
Bit 6		Reserved				1
Bit 5	Reserved					
Bit 4	Reserved					
Bit 3		Reserved				1
Bit 2	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 1	DIF OE0 Output Enable RW Low/Low Enabled					
Bit 0		Reserved				1

SMBus Table: SS Readback and Vhigh Control Register

Byte 1	Name	Control Function	Туре	0	1	Default
Bit 7	SSENRB1	SS Enable Readback Bit1	R	00' for SS_EN_tri =	0, '01' for SS_EN_tri	Latch
Bit 6	SSENRB1	SS Enable Readback Bit0	R	= 'M', '11 for S	S_EN_tri = '1'	Latch
Bit 5	SSEN_SWCNTRL	Enable SW control of SS	RW	I SS control locked	Values in B1[4:3] control SS amount.	0
Bit 4	SSENSW1	SS Enable Software Ctl Bit1	RW ¹	00' = SS Off, '0'	1' = -0.25% SS,	0
Bit 3	SSENSW0	SS Enable Software Ctl Bit0	RW ¹	'10' = Reserved	, '11'= -0.5% SS	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.55V	01 = 0.65V	1
Bit 0	AMPLITUDE 0	Controls Output Ampiltude	RW	10= 0.7V	11 = 0.8V	0

^{1.} B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				1
Bit 6		Reserved				1
Bit 5	Reserved					
Bit 4	Reserved					
Bit 3		Reserved				1
Bit 2	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow Setting	Fast Setting	1
Bit 1	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow Setting	Fast Setting	1
Bit 0		Reserved				1

SMBus Table: REF Control Register

Byte 3	Name	Control Function	Туре	0	1	Default
Bit 7	REF	Slew Rate Control	RW	00 = Slowest	01 = Slow	0
Bit 6	, KEF	Siew Rate Control	RW	10 = Fast	11 = Faster	1
Bit 5	REF Power Down Function	Wake-on-Lan Enable for REF	RW	REF does not run in Power Down	REF runs in Power Down	0
Bit 4	REF OE	REF Output Enable	RW	Low	Enabled	1
Bit 3		Reserved	•			1
Bit 2		Reserved				
Bit 1	Reserved					1
Bit 0		Reserved				1

Byte 4 is reserved and reads back 'hFF'.



SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R			0
Bit 6	RID2	Revision ID	R	A rev =	- 0000	0
Bit 5	RID1	INCUSION ID	R	7 164 -	0	
Bit 4	RID0		R	1	0	
Bit 3	VID3		R		0	
Bit 2	VID2	VENDOR ID	R	0001	0001 = IDT	
Bit 1	VID1	VENDOR ID	R	0001		
Bit 0	VID0		R	1	1	

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Type	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx, 01 =	DBx ZDB/FOB,	0
Bit 6	Device Type0	Device Type	R	10 = DMx, 11= DBx FOB		0
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R		0	
Bit 3	Device ID3	Device ID	R	00010 bina	00010 binary or 02 hex	
Bit 2	Device ID2	Device ib	R	000 TO DITIAL		
Bit 1	Device ID1		R			1
Bit 0	Device ID0		R			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				0
Bit 6	Reserved					0
Bit 5	Reserved					0
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist	er will configure how	1
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	read back, default is	0
Bit 1	BC1		RW	= 8 b	ytes.	0
Bit 0	BC0		RW			0

Recommended Crystal Characteristics (3225 package)

PARAMETER	VALUE	VALUE UNITS	
Frequency	25	MHz	1
Resonance Mode	Fundamental	ı	1
Frequency Tolerance @ 25°C	±20	PPM Max	1
Frequency Stability, ref @ 25°C Over Operating Temperature Range	±20	PPM Max	1
Temperature Range (commerical)	0~70	°C	1
Temperature Range (industrial)	-40~85	°C	2
Equivalent Series Resistance (ESR)	50	Ω Max	1
Shunt Capacitance (C _O)	7	pF Max	1
Load Capacitance (C _L)	8	pF Max	1
Drive Level	0.3	mW Max	1
Aging per year	±5	PPM Max	1

Notes:

- 1. FOX 603-25-150.
- 2. For I-temp, FOX 603-25-261.



Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
Thermal Resistance	θ_{JC}	Junction to Case	NLG24 62 5.4 50 43 39	62	°C/W	1
	θ_{Jb}	Junction to Base		5.4	°C/W	1
	θ_{JA0}	Junction to Air, still air		50	°C/W	1
	θ_{JA1}	Junction to Air, 1 m/s air flow		43	°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow		°C/W	1	
	θ_{JA5}	Junction to Air, 5 m/s air flow		38	°C/W	1

¹ePad soldered to board

Marking Diagrams



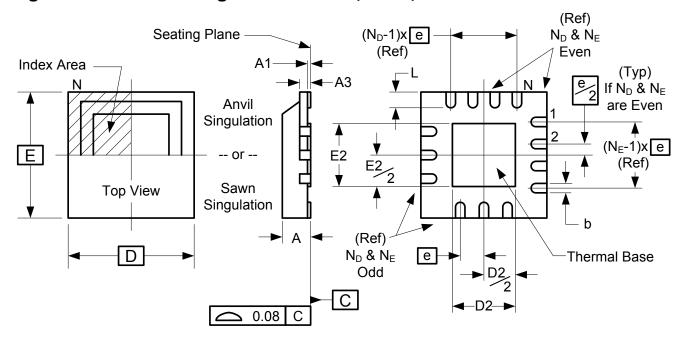


Notes:

- 1. "LOT" is the lot number.
- 2. "YYWW" is the last two digits of the year and week that the part was assembled.
- 3. "L" denotes RoHS compliant package.
- 4. "I" denotes industrial temperature grade.



Package Outline and Package Dimensions (NLG24)



	Millimeters		
Symbol	Min	Max	
Α	0.80	1.00	
A1	0	0.05	
A3	0.25 Reference		
b	0.18	0.30	
е	0.50 BASIC		
D x E BASIC	4.00 x 4.00		
D2 MIN./MAX.	2.3	2.60	
E2 MIN./MAX.	2.3	2.60	
L MIN./MAX.	0.30	0.50	
N	24		
N _D	6		

Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9FGU0231AKLF	Tubes	24-pin VFQFPN	0 to +70° C
9FGU0231AKLFT	Tape and Reel	24-pin VFQFPN	0 to +70° C
9FGU0231AKILF	Tubes	24-pin VFQFPN	-40 to +85° C
9FGU0231AKILFT	Tape and Reel	24-pin VFQFPN	-40 to +85° C

[&]quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

[&]quot;A" is the device revision designator (will not correlate with the datasheet revision).



Revision History

Rev.	Issue Date	Intiator	Description	Page #
А	9/24/2014	RDW	Updated electrical tables with latest versions for release Updated SMBus nomenclature for consistency with the family Removed references to Suspend Mode. This is replaced by Power Down with Wake-on-LAN Modes in the current consumption table. Updated GenDes tab for front page consistency All Electrical tables updated with characterization data. Move to final.	Various
В	10/18/2016	RDW	Removed IDT crystal part number	



IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Rev.1.0 Mar 2020)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:

www.renesas.com/contact/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Clock Generators & Support Products category:

Click to view products by Renesas manufacturer:

Other Similar products are found below:

CV183-2TPAG 950810CGLF 9DBV0741AKILF 9VRS4420DKLF CY25404ZXI226 CY25422SXI-004 MPC9893AE NB3H515001MNTXG PL602-20-K52TC ICS557GI-03LF PI6LC48P0101LIE 82P33814ANLG 840021AGLF ZL30244LFG7 PI6LC48C21LE
ZL30245LFG7 PI6LC48P0405LIE PI6LC48P03LE MAX24505EXG+ ZL30163GDG2 5L1503L-000NVGI8 ZL30156GGG2 ZL30673LFG7
MAX24188ETK2 ZL30152GGG2 5L1503-000NVGI8 PI6C557-01BZHIEX PI6LC48C21LIE CY2542QC002 5P35023-106NLGI
5X1503L-000NLGI8 ZL30121GGG2V2 ZL30282LDG1 ZL30102QDG1 ZL30159GGG2 DS1070K ZL30145GGG2 ZL30312GKG2
MAX24405EXG2 ZL30237GGG2 SY100EL34LZG 9FGV1002BQ506LTGI AD9518-4ABCPZ MX852BB0030 PI6LC4840ZHE AD95160BCPZ-REEL7 AD9574BCPZ-REEL7 PL602-21TC-R ZL30105QDG1 ZL30100QDG1